TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74HCT574AP,TC74HCT574AF

Octal D-Type Flip-Flop with 3-State Output

The TC74HCT574A is a high speed CMOS OCTAL FLIP-FLOP with 3-STATE OUTPUT fabricated with silicon gate C^2MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Its inputs are compatible with TTL, NMOS, and CMOS output voltage levels.

Its 8-bit D-type flip-flops is controlled by a clock input (CK) and an output enable input (\overline{OE}).

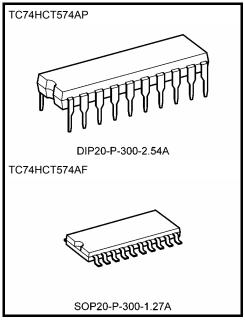
All inputs are equipped with protection circuits against static discharge or transient excess voltage.

Features

- High speed: $f_{max} = 62 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- Low power dissipation: $I_{CC} = 4 \mu A \text{ (max)}$ at $T_{a} = 25 \text{°C}$
- Compatible with TTL outputs: V_{IL} = 0.8 V (min)

 $V_{IH} = 2.0 \text{ V (max)}$

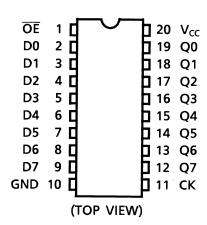
- Output drive capability: 15 LSTTL loads
- Symmetrical output impedance: $|I_{OH}| = I_{OL} = 6 \text{ mA (min)}$
- Balanced propagation delays: $t_{pLH} \simeq t_{pHL}$
- Pin and function compatible with 74LS574



Weight

DIP20-P-300-2.54A : 1.30 g (typ.) SOP20-P-300-1.27A : 0.22 g (typ.)

Pin Assignment



IEC Logic Symbol

OE (1) CK (11)	EN C1		
D0 (2) (3) (4) (5) (5) (6) (7) D5 (8) D6 (9) D7	1D	▷ ♡	(19) Q0 (18) Q1 (17) Q2 (16) Q3 (15) Q4 (14) Q5 (13) Q6 (12) Q7

Truth Table

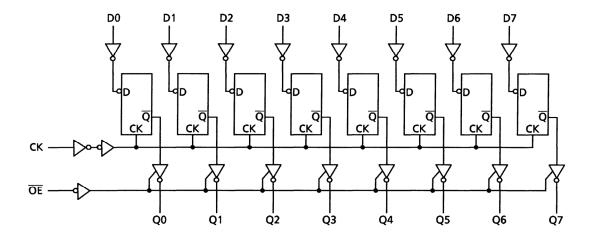
	Output		
ŌĒ	CK	D	Q
Н	Х	Х	Z
L	\rightarrow	Х	Qn
L		L	L
L		Н	Н

X: Don't care

Z: High impedance

Q_n: No change

System Diagram



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Absolute Maximum Ratings (Note 1)

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Characteristics	Symbol	Rating	Unit
Supply voltage range	V _{CC}	-0.5~7	V
DC input voltage	V _{IN}	-0.5~V _{CC} + 0.5	V
DC output voltage	V _{OUT}	-0.5~V _{CC} + 0.5	V
Input diode current	l _{IK}	±20	mA
Output diode current	lok	±20	mA
DC output current	lout	±35	mA
DC V _{CC} /ground current	Icc	±75	mA
Power dissipation	PD	500 (DIP) (Note 2)/180 (SOP)	mW
Storage temperature	T _{stg}	−65 ~ 150	°C

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: 500 mW in the range of Ta = -40 to $65^{\circ}C$. From Ta = 65 to $85^{\circ}C$ a derating factor of -10 mW/°C shall be applied until 300 mW.

Operating Ranges (Note)

Characteristics	Symbol	Rating	Unit
Supply voltage	V _{CC}	4.5~5.5	V
Input voltage	V _{IN}	0~V _{CC}	V
Output voltage	Vout	0~V _{CC}	V
Operating temperature	T _{opr}	-40~85	°C
Input rise and fall time	t _r , t _f	0~500	ns

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either VCC or GND.

Electrical Characteristics

DC Characteristics

Characteristics Symbol		Test Condition $V_{CC}\left(V\right)$		-	Га = 25°0		Ta = -40~85°C		Unit	
				V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
High-level input voltage	V _{IH}	_		4.5~5.5	2.0	_	_	2.0	_	V
Low-level input voltage	V _{IL}		_		_	_	0.8	_	0.8	٧
High-level output	V _a V _{IN}		$I_{OH} = -20 \mu A$	4.5	4.4	4.5		4.4	_	V
voltage	VOH	= V _{IH} or V _{IL}	I _{OH} = -6 mA	4.5	4.18	4.31	_	4.13	_	V
Low-level output	V _{OL}	V _{IN}	$I_{OL} = 20 \mu A$	4.5	_	0.0	0.1		0.1	V
voltage	VOL	= V _{IH} or V _{IL}	I _{OL} = 6 mA	4.5	_	0.17	0.26	_	0.33	v
3-state output off-state current	I _{OZ}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		5.5	_	_	±0.5	_	±5.0	μА
Input leakage current	I _{IN}	V _{IN} = V _{CC} or GND		5.5	_	_	±0.1	_	±1.0	μА
Quiescent supply		$V_{IN} = V_{CC}$ or GND 5.5		5.5	_		4.0		40.0	μΑ
current	IC	Per input: V _{II} Other input:	$_{N}$ = 0.5 V or 2.4 V $_{CC}$ or GND	5.5		_	2.0	_	2.9	mA

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Timing Requirements (input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40 ~85°C	Unit	
			V _{CC} (V)	Тур.	Limit	Limit		
Minimum pulse width	t _{W (H)}		4.5	_	15	19	no	
(CK)	t _{W (L)}	_	5.5	_	14	17	ns	
Minimum set-up time	4		4.5	_	15	19		
(Dn)	t _S	_	5.5	_	14	17	ns	
Minimum hold time	4.		4.5	_	0	0		
(Dn)	t _h	_	5.5	_	0	0	ns	
Clask framesa.	£		4.5	_	31	25	MHz	
Clock frequency	Clock frequency f	_	5.5	_	34	27	IVI⊓Z	

AC Characteristics (input: $t_r = t_f = 6$ ns)

Characteristics Symbol		Test Condition			Ta = 25°C			Ta = -4	Unit	
Characteristics	Symbol		CL (pF)	V _{CC} (V)	Min	Тур.	Max	Min	Max	Offic
Output transition time	t _{TLH}		50	4.5	_	7	12	_	15	
Output transition time	t _{THL}		30	5.5		6	11	_	14	ns
			50	4.5		19	30	_	38	
Propagation delay time	t_{pLH}		30	5.5		16	27	_	34	ns
(CK-Q)	t_{pHL}		150	4.5	_	24	40	_	48	115
,			150	5.5		21	35	_	44	
			50	4.5		19	30	_	38	- ns
Output enable time	t_{pZL}	$R_L = 1 \text{ k}\Omega$		5.5	_	16	27	_	34	
Output enable time	t_{pZH}		150	4.5	_	24	40	_	48	
			150	5.5	_	21	35	_	44	
Output disable time	t_{pLZ}	$R_L = 1 k\Omega$	50	4.5		19	30	_	38	ns
Output disable time	t_{pHZ}	K[= 1 K22	30	5.5	_	16	27	_	34	115
Maximum clock	ı		50	4.5	31	50	_	25	_	MHz
frequency	f _{max}		30	5.5	34	60	_	27	_	IVITZ
Input capacitance	C _{IN}		-		_	5	10	_	10	pF
Output capacitance	C _{OUT}	_	_		_	10	_	_	_	pF
Power dissipation	C _{PD}					62				pF
capacitance	(Note)		_			02				Ы

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC}$$
 (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8$ (per bit)

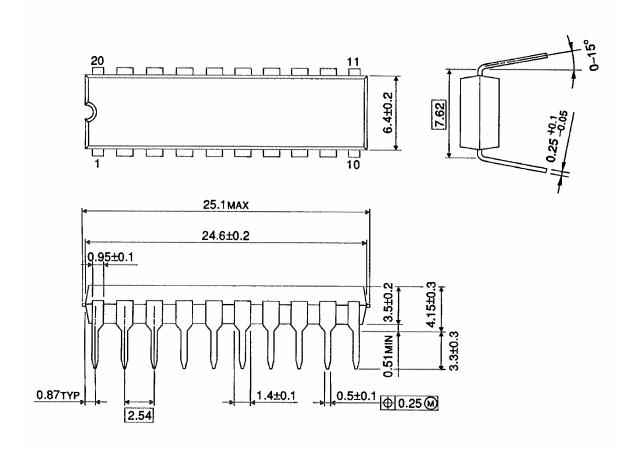
And the total CPD when n pcs. of flip flop operate can be gained by the following equation:

$$C_{PD}$$
 (total) = 47 + 15 · n

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Package Dimensions

DIP20-P-300-2.54A Unit: mm

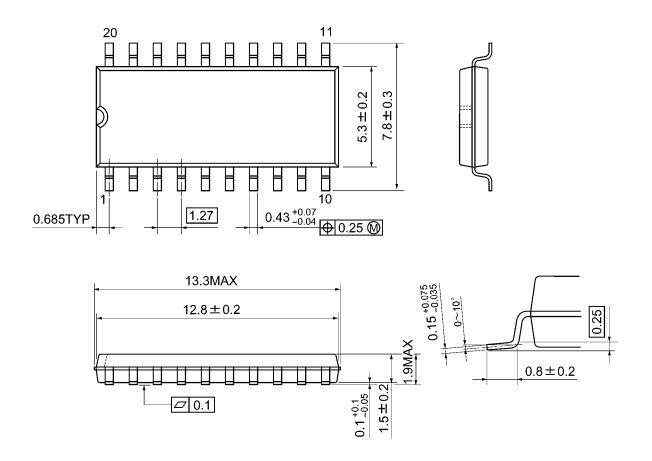


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Weight: 1.30 g (typ.)

Package Dimensions

SOP20-P-300-1.27A Unit: mm



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Weight: 0.22 g (typ.)

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20070701-EN GENERAL

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